

## Description

This bipolar junction transistor (BJT) is designed to meet the stringent requirements of automotive applications.

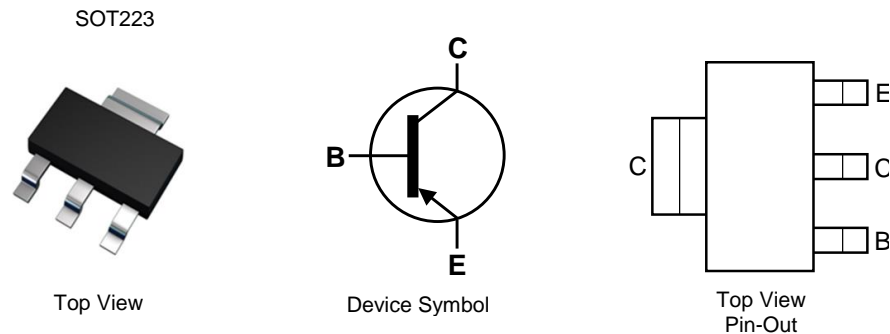
## Features

- $BV_{CEO} > -100V$
- $I_C = -2A$  High Continuous Current
- $I_{CM} = -6A$  Peak Pulse Current
- Low Saturation Voltage  $V_{CE(sat)} < -300mV @ -1A$
- Complementary NPN Type: DIODES™ FZT653
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen- and Antimony-Free. "Green" Device (Note 3)**
- **The DIODES™ FZT753Q is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF16949 certified facilities.**

<https://www.diodes.com/quality/product-definitions/>

## Mechanical Data

- Package: SOT223 (Type DN)
- Package Material: Molded Plastic. "Green" Molding Compound; UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.112 grams (Approximate)

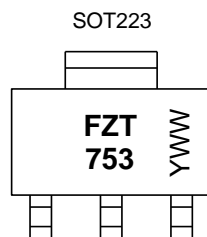


## Ordering Information (Note 4)

Part Number	Package	Marking	Reel Size (inches)	Tape Width (mm)	Packing	
					Qty.	Carrier
FZT753QTA	SOT223 (Type DN)	FZT753	7	12	1,000	Reel
FZT753QTC	SOT223 (Type DN)	FZT753	13	12	4,000	Reel

- Notes:
1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
  2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
  4. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

## Marking Information



FZT 753 = Product Type Marking Code  
 YWW = Date Code Marking  
 Y or  $\bar{Y}$  = Last Digit of Year (ex: 2 = 2022)  
 WW or  $\bar{W}W$  = Week Code (01~53)

**Absolute Maximum Ratings** (@  $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	$V_{CBO}$	-120	V
Collector-Emitter Voltage	$V_{CEO}$	-100	V
Emitter-Base Voltage	$V_{EBO}$	-7	V
Continuous Collector Current	$I_C$	-2	A
Peak Pulse Current	$I_{CM}$	-6	A

**Thermal Characteristics** (@  $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

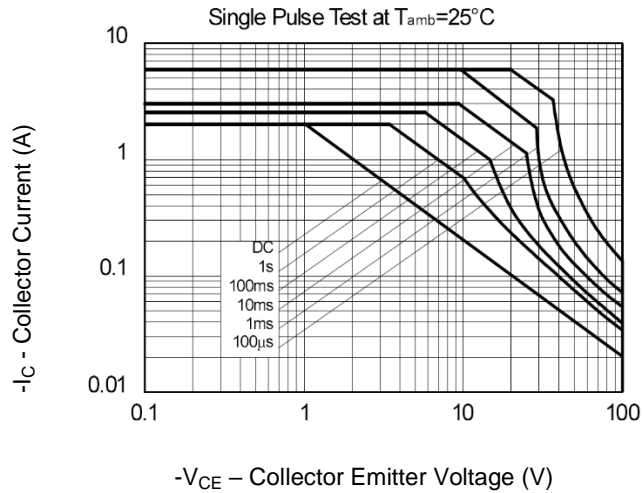
Characteristic	Symbol	Value	Unit
Power Dissipation	$P_D$	(Note 5)	3.0
		(Note 6)	2.0
		(Note 7)	1.6
		(Note 8)	1.2
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	(Note 5)	41.7
		(Note 6)	62.5
		(Note 7)	78.1
		(Note 8)	104
Thermal Resistance Junction to Lead	$R_{\theta JL}$	12.9	
Operating and Storage Temperature Range	$T_J, T_{STG}$	-55 to +150	$^\circ\text{C}$

**ESD Ratings** (Note 10)

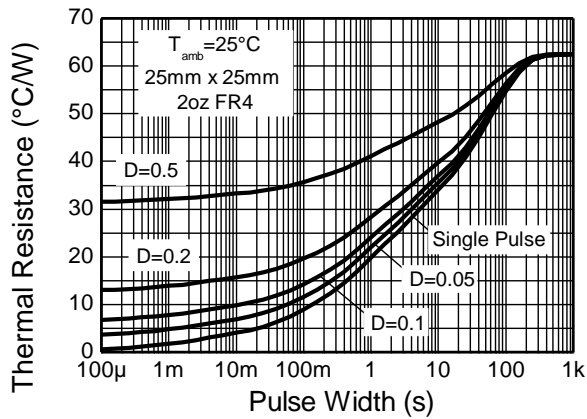
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	C

- Notes:
5. For a device mounted with the collector lead on 50mm x 50mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
  6. Same as Note 5, except the device is mounted on 25mm x 25mm 2oz copper.
  7. Same as Note 5, except the device is mounted on 25mm x 25mm 1oz copper.
  8. Same as Note 5, except the device is mounted on minimum recommended pad layout.
  9. Thermal resistance from junction to solder-point (at the end of the collector lead).
  10. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

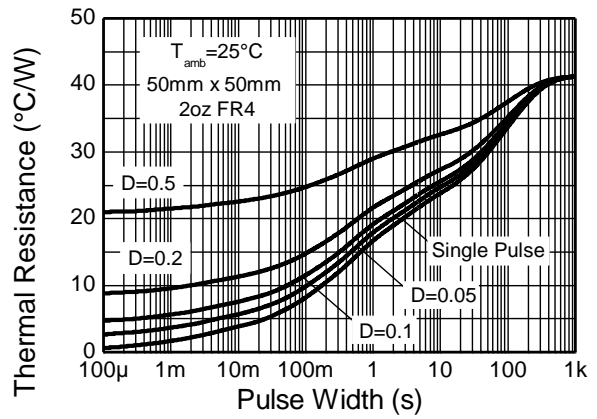
**Thermal Characteristics and Derating Information**



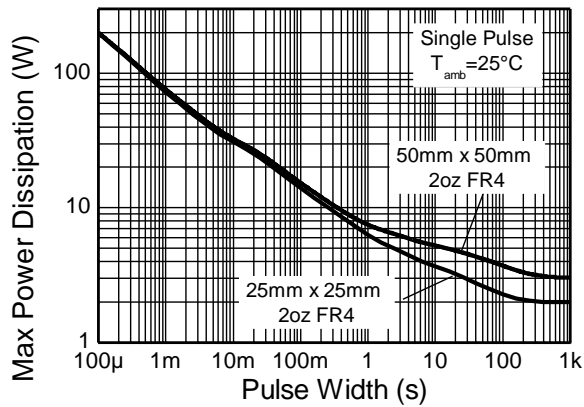
**Figure 1. Safe Operating Area**



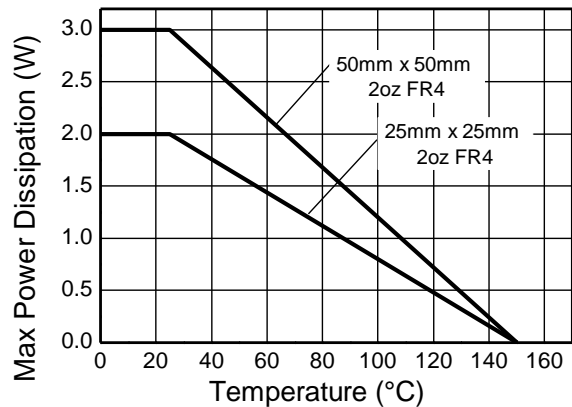
**Figure 2. Transient Thermal Impedance**



**Figure 3. Transient Thermal Impedance**



**Figure 4. Power Pulse Dissipation**



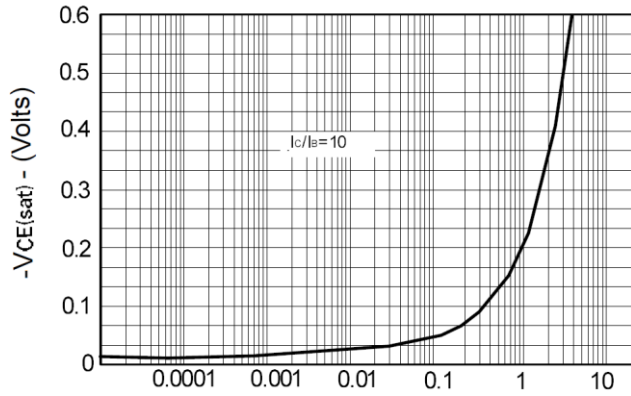
**Figure 5. Derating Curve**

**Electrical Characteristics** (@  $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	$BV_{CBO}$	-120	–	–	V	$I_C = -100\mu\text{A}$
Collector-Emitter Breakdown Voltage (Note 11)	$BV_{CEO}$	-100	–	–	V	$I_C = -1\text{mA}$
Emitter-Base Breakdown Voltage	$BV_{EBO}$	-7	–	–	V	$I_E = -100\mu\text{A}$
Collector Cut-Off Current	$I_{CBO}$	–	1	-100	nA	$V_{CB} = -100\text{V}$
		–	–	-10	$\mu\text{A}$	$V_{CB} = -100\text{V}$ , $T_A = +125^\circ\text{C}$
Emitter Cut-Off Current	$I_{EBO}$	–	1	-100	nA	$V_{EB} = -5.6\text{V}$
Collector-Emitter Saturation Voltage (Note 11)	$V_{CE(sat)}$	–	-0.17	-0.3	V	$I_C = -1\text{A}$ , $I_B = -100\text{mA}$
		–	-0.30	-0.5		$I_C = -2\text{A}$ , $I_B = -200\text{mA}$
Base-Emitter Saturation Voltage (Note 11)	$V_{BE(sat)}$	–	-0.9	-1.25	V	$I_C = -1\text{A}$ , $I_B = -100\text{mA}$
Base-Emitter Turn-On Voltage (Note 11)	$V_{BE(on)}$	–	-0.8	-1.0	V	$I_C = -1\text{A}$ , $V_{CE} = -2\text{V}$
DC Current Gain (Note 11)	$h_{FE}$	70	200	–	–	$I_C = -50\text{mA}$ , $V_{CE} = -2\text{V}$
		100	200	300		$I_C = -500\text{mA}$ , $V_{CE} = -2\text{V}$
		55	170	–		$I_C = -1\text{A}$ , $V_{CE} = -2\text{V}$
		25	55	–		$I_C = -2\text{A}$ , $V_{CE} = -2\text{V}$
Current Gain-Bandwidth Product	$f_T$	100	140	–	MHz	$V_{CE} = -5\text{V}$ , $I_C = -100\text{mA}$ $f = 100\text{MHz}$
Turn-On Time	$t_{on}$	–	40	–	ns	$V_{CC} = -10\text{V}$ , $I_C = -500\text{mA}$
Turn-Off Time	$t_{off}$	–	600	–	ns	$I_{B1} = -I_{B2} = -50\text{mA}$
Output Capacitance	$C_{obo}$	–	–	30	pF	$V_{CB} = -10\text{V}$ , $f = 1\text{MHz}$

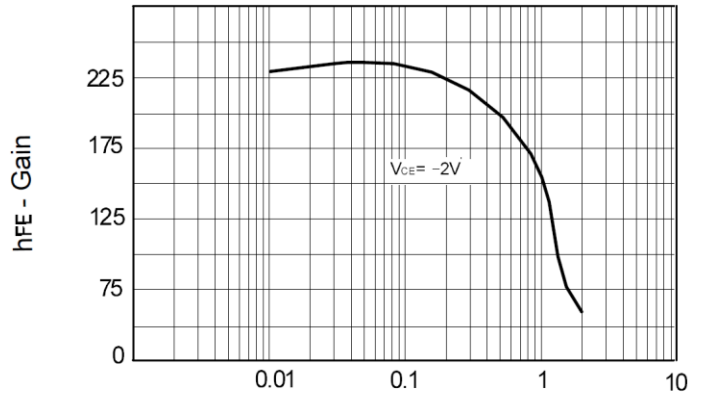
Note: 11. Measured under pulsed conditions. Pulse width  $\leq 300\mu\text{s}$ . Duty cycle  $\leq 2\%$ .

**Typical Electrical Characteristics** (@  $T_A = +25^\circ\text{C}$ , unless otherwise specified.)



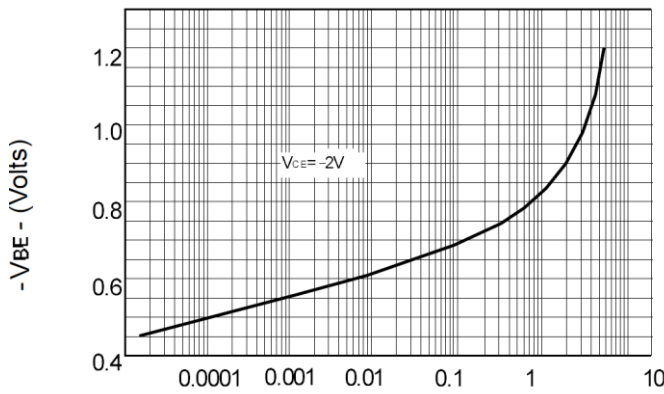
-Ic - Collector Current (Amps)

**Figure 6.  $V_{CE(sat)} \ v \ I_c$**



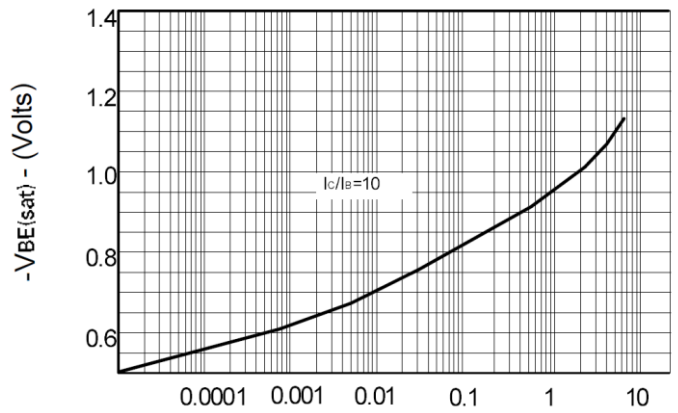
-Ic - Collector Current (Amps)

**Figure 7.  $h_{FE} \ v \ I_c$**



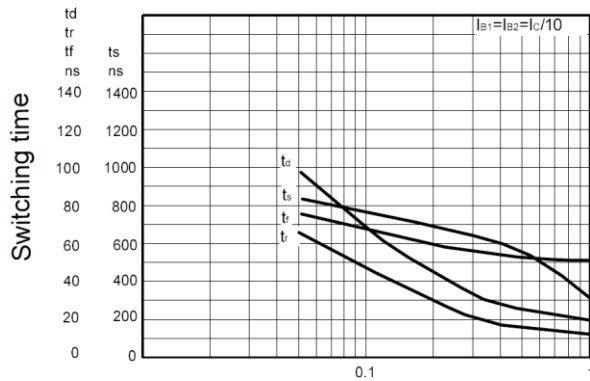
-Ic - Collector Current (Amps)

**Figure 8.  $V_{BE(on)} \ v \ I_c$**



-Ic - Collector Current (Amps)

**Figure 9.  $V_{BE(sat)} \ v \ I_c$**



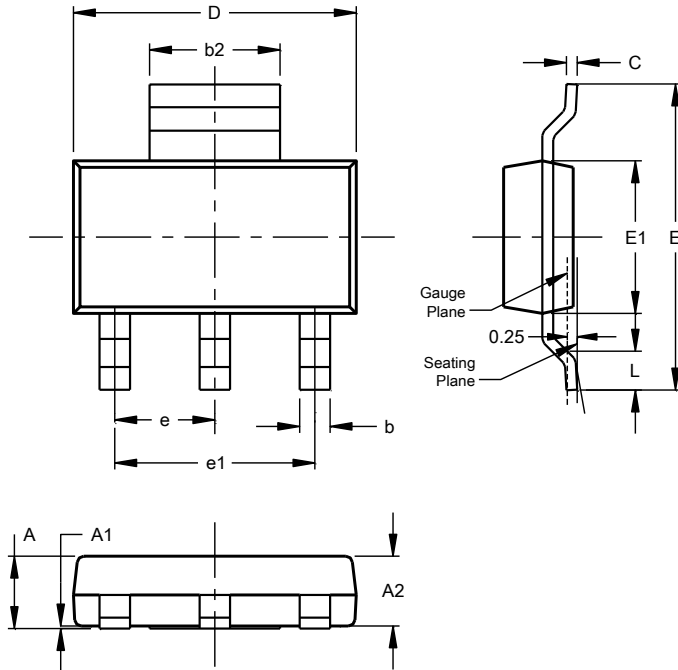
-Ic - Collector Current (Amps)

**Figure 10. Switching Speed**

## Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

SOT223 (Type DN)

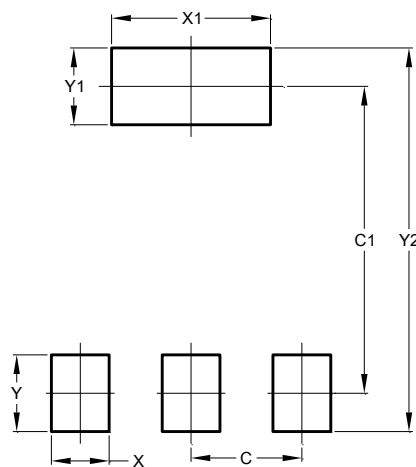


SOT223 (Type DN)			
Dim	Min	Max	Typ
A	--	1.70	--
A1	0.01	0.15	--
A2	1.50	1.68	1.60
b	0.60	0.80	0.70
b2	2.90	3.10	--
c	0.20	0.32	--
D	6.30	6.70	--
E	6.70	7.30	--
E1	3.30	3.70	--
e	--	--	2.30
e1	--	--	4.60
L	0.85	--	--
All Dimensions in mm			

## Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

SOT223 (Type DN)



Dimensions	Value (in mm)
C	2.30
C1	6.40
X	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00

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